

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	2459	438/149	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/15 09:41
L2	2459	L1	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/15 09:41
L3	2188	438/151	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/15 09:41
L4	2188	438/151	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/15 09:51
L5	447	438/153	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/15 10:26
L6	1541	438/455	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/15 10:27
L7	357	438/456	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/15 10:27
L8	3490	438/622	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/15 10:27
L9	79185	(thin adj2 film adj2 transistor) or tft	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/15 10:27

L10	107985	(substrate or wafer) near3 (bond\$)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/15 10:27
L11	691	257/69	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/15 10:44
L12	17726	L10 same (insulat\$ or dielectric)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/15 10:45
L13	217290	(substrate or wafer)near3 (remov\$ or etch\$)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/15 10:45
L14	2074	L12 same L13	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/15 10:45
L15	2074	L14	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/15 10:45
L16	148	"5166556"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/15 10:47
L17	38	((("5206749") or ("5256562") or ("5258325") or ("5317236") or ("5331149") or ("5376561") or ("5376979") or ("5396304") or ("5444557") or ("5467154") or ("5475514") or ("5581385") or ("5661371") or ("5666175") or ("5692820") or ("5743614") or ("5751261") or ("5861929") or ("6022792") or ("6043800") or ("6072445") or ("6320568") or ("6424020"))).PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/15 10:58

L18	26	((("5376561") or ("5643826") or ("5757456") or ("5766977") or ("5834327") or ("6127199") or ("6133626") or ("6258623") or ("6317175") or ("6022792") or ("6423614") or ("5757456") or ("5953595")).PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/15 11:08
L19	36	"5612552"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/15 11:48
L20	24	"5705424"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/15 11:49
L21	3	"6608654"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/15 11:51
L22	1	"5166816".PN.	USPAT; USOCR	OR	ON	2005/08/15 11:50
L23	1	"5117298".PN.	USPAT; USOCR	OR	ON	2005/08/15 11:50
L24	1	"5317236".PN.	USPAT; USOCR	OR	ON	2005/08/15 11:50
L25	1	"5256562".PN.	USPAT; USOCR	OR	ON	2005/08/15 11:50
L26	1	"5117298".PN.	USPAT; USOCR	OR	ON	2005/08/15 11:51
L27	11	"6500694"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/15 11:53
L28	1	"6270202".PN.	USPAT; USOCR	OR	ON	2005/08/15 11:53
L29	1	"6236141".PN.	USPAT; USOCR	OR	ON	2005/08/15 11:53
L30	2	"6525415"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/15 11:53
L31	1	"6322903".PN.	USPAT; USOCR	OR	ON	2005/08/15 11:53

S1	2459	438/149	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/14 12:07
S2	2188	438/151	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/14 10:44
S3	447	438/153	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/14 10:44
S4	1541	438/455	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/14 10:44
S5	357	438/456	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/14 10:44
S6	3490	438/622	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/14 10:45
S7	222	438/928	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/14 10:45
S8	478	438/977	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/14 10:45
S9	1860	438/149	USPAT	OR	ON	2005/08/14 12:19
S10	0	S9 not S1	USPAT	OR	ON	2005/08/14 12:07
S11	1329	S2 not S1	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/14 12:19

S12	292	S3 not S1	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/14 12:19
S13	1564	S11 or S12	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/14 12:54
S14	1683	S4 or S5	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/14 12:55
S15	0	S13 not (S1 or S2 or S3)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/14 12:56
S16	1683	S4 or S5	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/14 12:56
S17	1541	S16 not (S1 or S2 or S3)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/14 13:30
S18	645	S7 or S8	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/14 13:38
S19	78959	(thin adj2 film adj2 transistor) or tft	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/14 13:38
S20	107846	(substrate or wafer) near3 (bond\$)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/14 13:39
S21	17706	S20 same (insulat\$ or dielectric)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/14 13:40

S22	217086	(substrate or wafer)near3 (remov\$ or etch\$)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/14 13:40
S23	2072	S21 same S22	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/14 13:52
S24	45	S19 same S23	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/14 13:44
S25	175	S19 and S23	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/14 13:44
S26	130	S25 not S24	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/14 13:44
S27	1897	S23 not S25	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/14 13:53
S28	252	S27 and (S1 or S2 or S3 or S4 or S5 or S6 or S7 or S8)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/14 14:05
S29	327776	three adj dimension\$	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/14 14:05
S30	336	S23 and S29	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/14 14:06
S31	222	S30 not (S28 or S26)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/15 11:44

S32	813	257/67	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/14 14:41
S33	691	257/69	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/14 14:17
S34	1275	S32 or S33	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/14 14:17
S35	246	257/70	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/14 14:17
S36	170	S35 not S32	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/14 14:44
S37	109	257/181	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/14 14:49
S38	53	257/182	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/14 14:49

Interference Search Printout

10/728903

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	14532	thin adj film adj transistor	US-PGPUB	OR	ON	2005/08/15 12:09
L2	4504	1.clm.	US-PGPUB	OR	ON	2005/08/15 12:10
L3	492	(fourth adj insulat\$).clm.	US-PGPUB	OR	ON	2005/08/15 12:11
L4	3466	(remov\$ adj3 substrate).clm.	US-PGPUB	OR	ON	2005/08/15 12:11
L5	7	3 and 4	US-PGPUB	OR	ON	2005/08/15 12:12
L6	4	1 and 5	US-PGPUB	OR	ON	2005/08/15 12:11
L7	296	(third adj contact).clm. and (fifth adj contact).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/15 12:13
L8	19	1 and 7	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/15 12:14
L9	0	4 and 7	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/15 12:13
L10	14	2 and 7	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/15 12:14